

#### **Features**

- Trench Power LV MOSFET Technology
- · Excellent Package for Heat Dissipation
- High Density Cell Design for Low R<sub>DS(ON)</sub>
- Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)
- · Moisture Sensitivity Level 1

#### **Maximum Ratings**

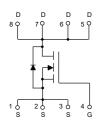
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 3.1°C/W Junction to Case<sup>(2)</sup>

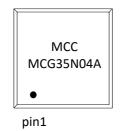
Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V <sub>DS</sub>	40	V
Gate-Source Volltage	$V_{GS}$	±20	V
Continuous Drain Current	I <sub>D</sub>	35	Α
Pulsed Drain Current <sup>(3)</sup>	I <sub>DM</sub>	160	Α
Total Power Dissipation	P <sub>D</sub>	40	W
Single Pulsed Avalanche Energy	E <sub>AS</sub>	120	mJ

#### Note:

- 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 2. Surface Mounted on 1 in<sup>2</sup> pad area, t ≤10 sec.
- 3. Pulse Test: Pulse Width≤300us, Duty cycle ≤2%.

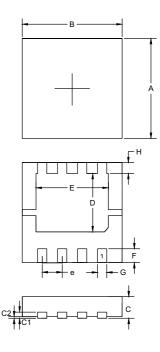
### **Internal Structure and Marking Code**





# N-CHANNEL MOSFET

## **DFN3333**



DIMENSIONS						
DIM INCHES		HES	MM		NOTE	
DIIVI	MIN	MAX	MIN	MAX	NOTE	
Α	0.126	0.130	3.20	3.30		
В	0.126	0.130	3.20	3.30		
С	0.030	0.033	0.75	0.85		
C1	0.007	0.009	0.18	0.22		
C2		0.002		0.05		
D	0.071	0.079	1.80	2.00		
Е	0.087	0.098	2.20	2.50		
F	0.016	0.020	0.40	0.50		
G	0.010	0.014	0.25	0.35		
Н	0.012	0.016	0.30	0.40		
е	0.024	0.028	0.60	0.70		

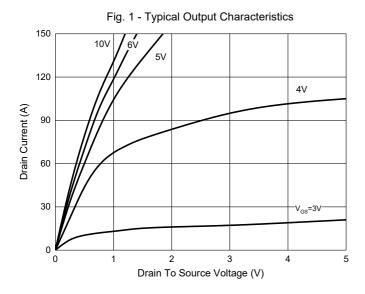


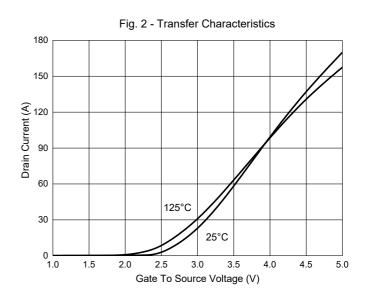
# Electrical Characteristics @ 25°C (Unless Otherwise Specified)

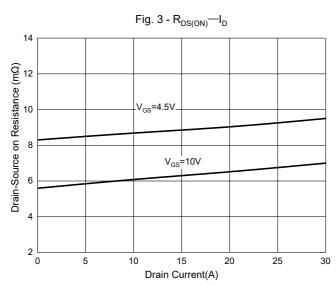
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Static Characteristics			'			
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250μA	40			V
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>DS</sub> =0V, V <sub>GS</sub> =±20V			±100	nA
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =40V, V <sub>GS</sub> =0V			1	μA
Gate-Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	1	1.5	2.5	V
Drain-Source On-Resistance		V <sub>GS</sub> =10V, I <sub>D</sub> =20A		6.5	8	mΩ
	$R_{DS(on)}$	V <sub>GS</sub> =4.5V, I <sub>D</sub> =10A		8.7	13	mΩ
Diode Characteristics						
Continuous Body Diode Current	Is				35	Α
Diode Forward Voltage	V <sub>SD</sub>	V <sub>GS</sub> =0V, I <sub>S</sub> =20A			1.2	V
Reverse Recovery Time	t <sub>rr</sub>	1 = 20 A d1 /d+= 100 A/u o		15		ns
Reverse Recovery Charge	Q <sub>rr</sub>	I <sub>F</sub> =20A, dI <sub>F</sub> /dt=100A/μs		2.3		nC
Dynamic Characteristics			,		•	
Input Capacitance	C <sub>iss</sub>			1860		
Output Capacitance	C <sub>oss</sub>	$V_{DS}$ =20V, $V_{GS}$ =0V,f=1MHz		256		pF
Reverse Transfer Capacitance	C <sub>rss</sub>			205		
Total Gate Charge	$Q_g$			46.7		
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ =20V, $V_{GS}$ =10V, $I_{D}$ =20A		8		nC
Gate-Drain Charge	$Q_{gd}$			11.6		
Turn-On Delay Time	t <sub>d(on)</sub>			10		
Turn-On Rise Time	t <sub>r</sub>	$V_{DS}$ =20V, $V_{GEN}$ =10V, $R_G$ =3 $\Omega$ , $R_L$ =1 $\Omega$ ,		21		no
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_{DS} = 2A$		36		ns
Turn-Off Fall Time	t <sub>f</sub>			25		

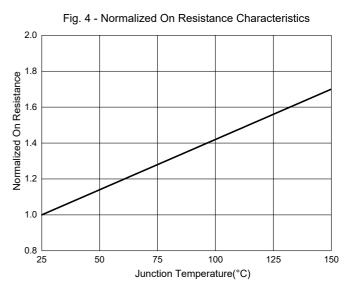


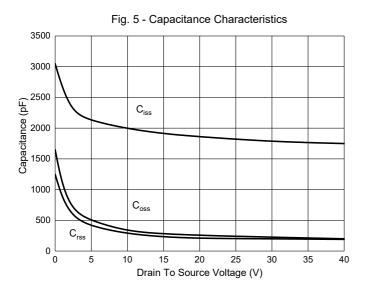
#### **Curve Characteristics**

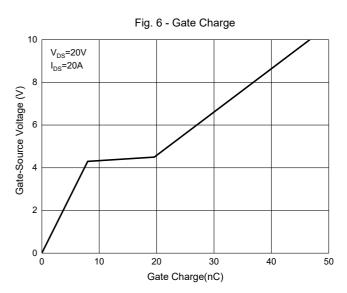








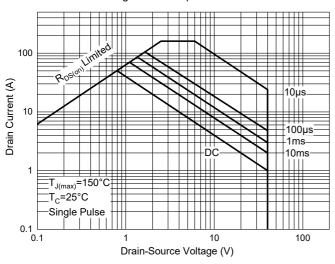






# **Curve Characteristics**







#### **Ordering Information**

Device	Packing	
Part Number-TP	Tape&Reel: 5Kpcs/Reel	

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